

FEATURES

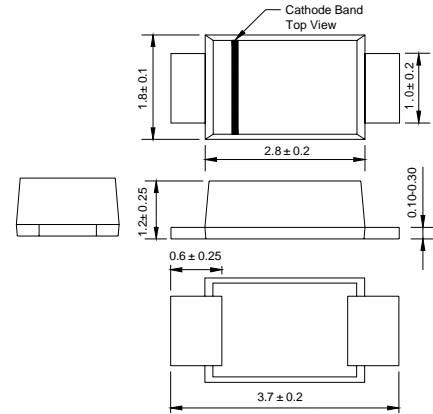
- Easy pick and place
- For surface mounted applications
- Low profile package
- Built-in strain relief
- Superfast recovery times for high efficiency

MECHANICAL DATA

- Case: SOD-123FL
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 15mg 0.00048oz



SOD-123FL



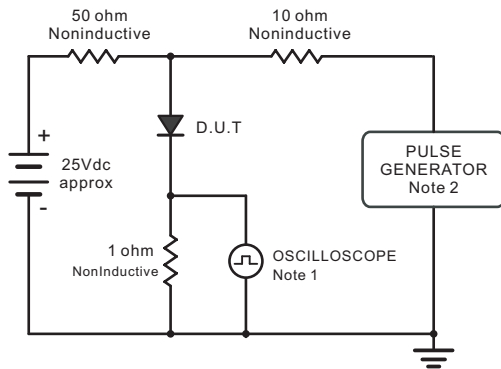
Dimensions in millimeters

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	ES1AW	ES1BW	ES1CW	ES1DW	ES1EW	ES1GW	ES1JW	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at $T_L = 100$ °C	$I_{F(AV)}$	1							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	25							A
Maximum Forward Voltage at 1 A	V_F	1				1.25		1.7	V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25$ °C $T_a = 125$ °C	I_R					5 100			μ A
Typical Junction Capacitance at $V_R=4V$, $f=1MHz$	C_j					10			pF
Maximum Reverse Recovery Time at $I_F=0.5A$, $I_R=1A$, $I_{rr}=0.25A$	t_{rr}					35			ns
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150							°C

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm, 22pF.
2. Rise Time = 10ns, max.
Source Impedance = 50 ohms.

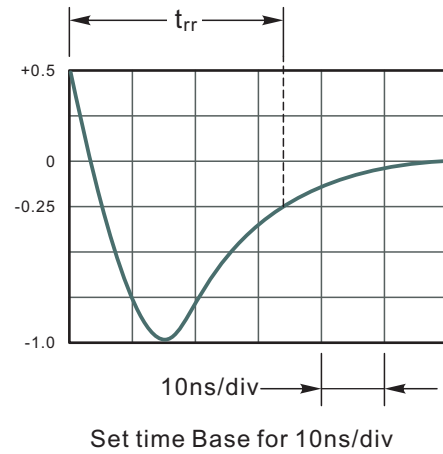


Fig.2 Maximum Average Forward Current Rating

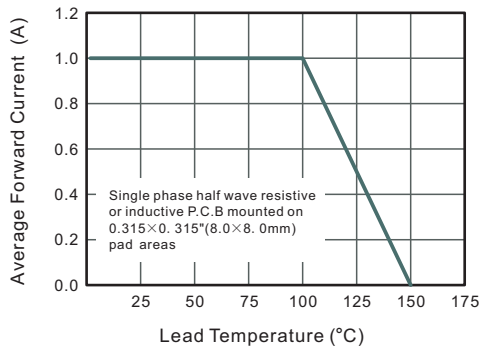


Fig.3 Typical Reverse Characteristics

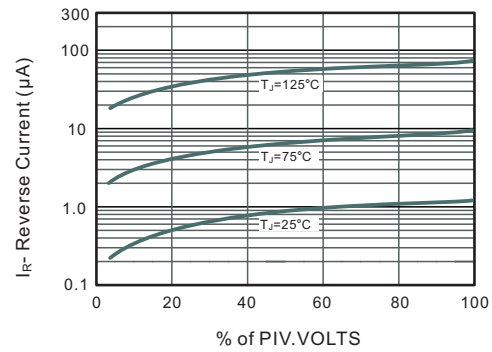


Fig.4 Typical Forward Characteristics

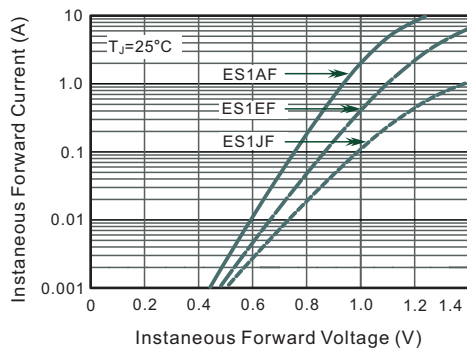


Fig.5 Typical Junction Capacitance

